BUK574-60H

GENERAL DESCRIPTION

N-channel enhancement mode logic level field-effect power transistor in a plastic full-pack envelope. The device is intended for use in Automotive applications, Switched Mode Power Supplies (SMPS), motor control, welding, DC/DC and AC/DC converters, and in general purpose switching applications.

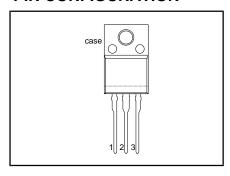
QUICK REFERENCE DATA

SYMBOL	PARAMETER	MAX.	UNIT
V _{DS} I _D Ptot T _j R _{DS(ON)}	Drain-source voltage Drain current (DC) Total power dissipation Junction temperature Drain-source on-state resistance; V _{GS} = 5 V	60 20 30 150 42	V A W °C mΩ

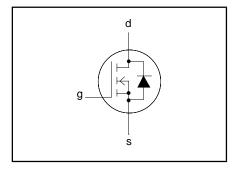
PINNING - SOT186A

PIN	DESCRIPTION
1	gate
2	drain
3	source
case	isolated

PIN CONFIGURATION



SYMBOL



LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _{DS}	Drain-source voltage	-	-	60	V
V_{DGR}	Drain-gate voltage	$R_{GS} = 20 \text{ k}\Omega$	-	60	V
±V _{GS}	Gate-source voltage	-	-	15	V
$\pm V_{GSM}$	Non-repetitive gate-source voltage	$t_p \le 50 \ \mu s$	-	20	V
I _D	Drain current (DC)	$T_{hs} = 25 ^{\circ}C$	-	20	Α
l _D	Drain current (DC)	T _{hs} = 100 °C	-	13.5	Α
I _{DM}	Drain current (pulse peak value)	$T_{hs}^{ro} = 25 ^{\circ}C$	-	80	Α
P _{tot}	Total power dissipation	$T_{hs}^{no} = 25 ^{\circ}C$	-	30	W
T _{stg}	Storage temperature	-	- 55	150	°C
T	Junction Temperature	-	-	150	°C

THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	TYP.	MAX.	UNIT
R _{th j-hs}	heatsink	With heatsink compound		4.17	K/W
R _{th j-a}	Thermal resistance junction to ambient		55	-	K/W

BUK574-60H

STATIC CHARACTERISTICS

 $T_{hs} = 25$ °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_{(BR)DSS}$	Drain-source breakdown voltage	$V_{GS} = 0 \text{ V}; I_{D} = 0.25 \text{ mA}$	60	1	1	٧
$V_{\text{GS(TO)}} \\ I_{\text{DSS}} \\ I_{\text{DSS}} \\ I_{\text{GSS}} \\ R_{\text{DS(ON)}}$	Gate threshold voltage	$\begin{aligned} &V_{DS} = V_{GS}; \ I_D = 1 \ mA \\ &V_{DS} = 60 \ V; \ V_{GS} = 0 \ V; \ T_j = 25 \ ^{\circ}C \\ &V_{DS} = 60 \ V; \ V_{GS} = 0 \ V; \ T_j = 125 \ ^{\circ}C \\ &V_{GS} = \pm 15 \ V; \ V_{DS} = 0 \ V \\ &V_{GS} = 5 \ V; \\ &I_D = 20 \ A \end{aligned}$	1.0 - - -	1.5 1 0.1 10 34	2.0 10 1.0 100 42	V μA mA nA mΩ

DYNAMIC CHARACTERISTICS

 T_{hs} = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
g fs	Forward transconductance	$V_{DS} = 25 \text{ V}; I_{D} = 20 \text{ A}$	10	18	-	S
C _{iss} C _{oss} C _{rss}	Input capacitance Output capacitance Feedback capacitance	$V_{GS} = 0 \text{ V}; V_{DS} = 25 \text{ V}; f = 1 \text{ MHz}$		1100 420 160	1750 600 275	pF pF pF
$egin{array}{c} t_{ ext{d on}} \ t_{ ext{r}} \ t_{ ext{d off}} \ t_{ ext{f}} \end{array}$	Turn-on delay time Turn-on rise time Turn-off delay time Turn-off fall time	$\begin{aligned} &V_{DD} = 30 \text{ V; } I_{D} = 3 \text{ A;} \\ &V_{GS} = 5 \text{ V; } R_{GS} = 50 \Omega; \\ &R_{gen} = 50 \Omega \end{aligned}$	- - - -	25 110 150 100	40 150 220 145	ns ns ns ns
L _d	Internal drain inductance Internal source inductance	Measured from drain lead 6 mm from package to centre of die Measured from source lead 6 mm from package to source bond pad	-	4.5 7.5	-	nH nH

ISOLATION LIMITING VALUE & CHARACTERISTIC

 T_{hs} = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{isol}	R.M.S. isolation voltage from all three terminals to external heatsink	f = 50-60 Hz; sinusoidal waveform; R.H. ≤ 65% ; clean and dustfree	ı		2500	>
C _{isol}	Capacitance from T2 to external heatsink	f = 1 MHz	1	10	-	pF

REVERSE DIODE LIMITING VALUES AND CHARACTERISTICS

 T_{hs} = 25 °C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{DR}	Continuous reverse drain current	-	-	-	20	Α
$I_{DRM} \ V_{SD}$	Pulsed reverse drain current Diode forward voltage	$I_F = 20 \text{ A}$; $V_{GS} = 0 \text{ V}$		- 0.9	80 2.0	A V
t _{rr} Q _{rr}	Reverse recovery time Reverse recovery charge	$I_F = 20 \text{ A}; -dI_F/dt = 100 \text{ A/}\mu\text{s};$ $V_{GS} = 0 \text{ V}; V_R = 30 \text{ V}$	-	60 0.25		ns μC

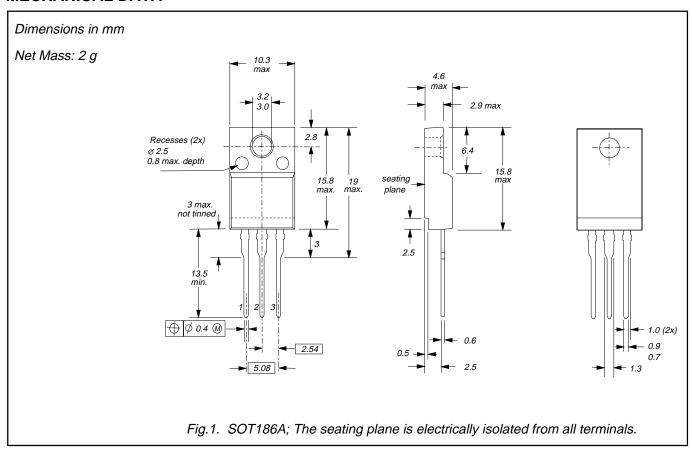
BUK574-60H

AVALANCHE LIMITING VALUE

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
W _{DSS}		$I_D = 41 \text{ A ; } V_{DD} \le 25 \text{ V ; } T_{hs} = 25 \text{ °C}$ $V_{GS} = 5 \text{ V ; } R_{GS} = 50 \Omega$,	1	90	mJ

BUK574-60H

MECHANICAL DATA



Notes

- 1. Observe the general handling precautions for electrostatic-discharge sensitive devices (ESDs) to prevent damage to MOS gate oxide.
- 2. Refer to mounting instructions for F-pack envelopes.
- 3. Epoxy meets UL94 V0 at 1/8".

BUK574-60H

DEFINITIONS

Data sheet status				
Objective specification	This data sheet contains target or goal specifications for product development.			
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.			
Product specification	This data sheet contains final product specifications.			
1 ''4'				

Limiting values

Limiting values are given in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of this specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

© Philips Electronics N.V. 1996

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract, it is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent or other industrial or intellectual property rights.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.